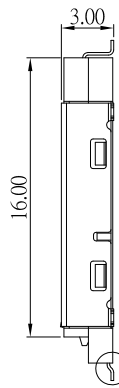
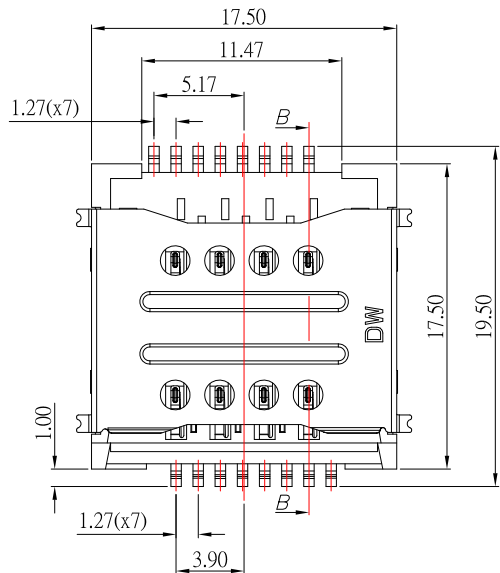
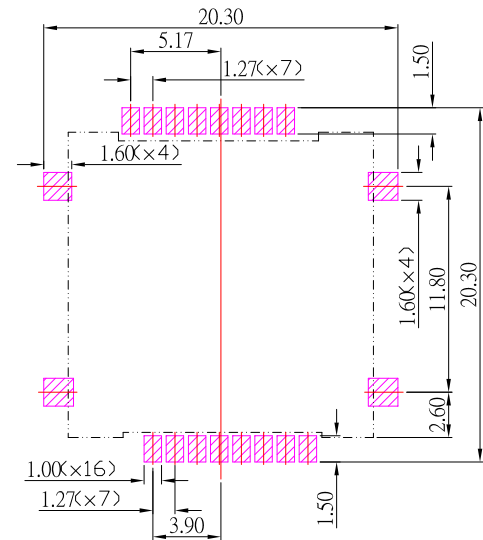
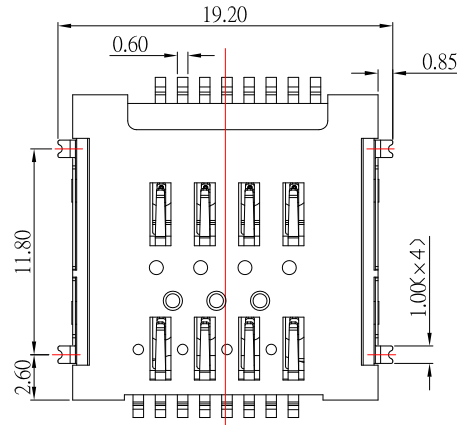


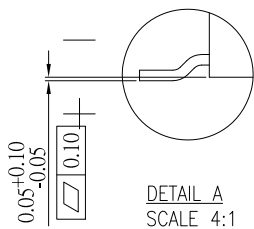
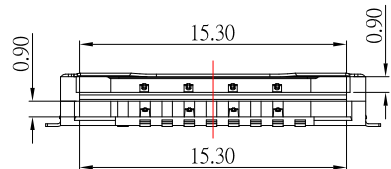
SECTION B-B



DETAIL A



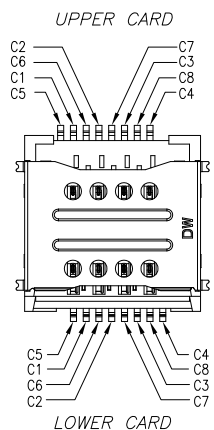
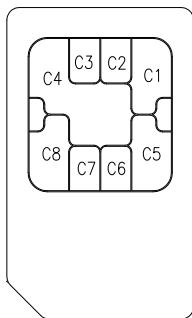
P.C.B LAYOUT MOUNTING PATTERN



DETAIL A SCALE 4:1

C1	C1:VCC
C2	C2:RST
C3	C3:CLK
C4	C4:RESERVED
C5	C5:GND
C6	C6:VPP
C7	C7:I/O
C8	C8:RESERVED

SIM CARD CIRCUIT



- MATERIALS:**
- HOUSING : HIGH TEMPERATURE THERMOPLASTIC
  - CONTACT : COPPER ALLOY
  - SHELL : SUS
- Finish:**
- Finish: CONTACT: PLATED GOLD IN MATING AREA ;  
TIN PLATED ON SOLDER BALLS ;  
NICKEL UNDER PLATED OVERALL
  - SHELL: NICKEL UNDER PLATED SURFACE LAYER

- SPECIFICATION:**
- INSULATION RESISTANCE : 1000MΩ MIN.
  - CONTACT RESISTANCE : 50mΩ MAX.
  - Dielectric Withstanding Voltage:350V AC
  - Durability:3000 cycles

**CONTACT** 建倚科技股份有限公司  
**CONTACT TECHNOLOGY CORP.**

TOLERANCE UNLESS OTHERWISE STATED :  
Up to 5 ±0.2  
Above 5 ~ 15 ±0.3  
Above 15 ~ 30 ±0.4  
Above 30 ~ 50 ±0.5  
Angle ±0.3

3RD. ANGEL'S

UNITS MM

DRAWN BY:	DATE	MAT'L	TITLE	CONNECTOR
Jack Lu	02/27/19			
CHECKED BY:	DATE	FINISH	MODLE	雙層SIM卡座H3.0
Jacky Chen	02/27/19			
APPROVED BY:	DATE	SCALE	DWG NO.	SIM-216D202-S267
Tony Kao	02/27/19	1 : 1		
		SHEET NO.	PART NO.	SIM-216D202-S267
		1 of 1		
				SIZE A4
				VER R

ITEM NO.	DESCRIPTION	DRAWN	DATE